

## FEATURES

- Wide Operating  $V_{IN}$  Range: Up to 80V
- Rugged Architecture Tolerant of 100V  $V_{IN}$  Transients
- Powerful  $1.5\Omega$  Driver Pull-Down
- Powerful 2.4A Peak Current Driver Pull-Up
- 7ns Fall Time Driving 1000pF Load
- 10ns Rise Time Driving 1000pF Load
- Drives Standard Threshold MOSFETs
- TTL/CMOS Compatible Inputs with Hysteresis
- Input Thresholds are Independent of Supply
- Undervoltage Lockout
- Low Profile (1mm) SOT-23 (ThinSOT)™ and Thermally Enhanced 8-Pin MSOP Packages

## APPLICATIONS

- Telecommunications Power Systems
- Distributed Power Architectures
- Server Power Supplies
- High Density Power Modules

## DESCRIPTION

The LTC<sup>®</sup>4440 is a high frequency high side N-channel MOSFET gate driver that is designed to operate in applications with  $V_{IN}$  voltages up to 80V. The LTC4440 can also withstand and continue to function during 100V  $V_{IN}$  transients. The powerful driver capability reduces switching losses in MOSFETs with high gate capacitances. The LTC4440's pull-up has a peak output current of 2.4A and its pull-down has an output impedance of  $1.5\Omega$ .

The LTC4440 features supply independent TTL/CMOS compatible input thresholds with 350mV of hysteresis. The input logic signal is internally level-shifted to the bootstrapped supply, which may function at up to 115V above ground.

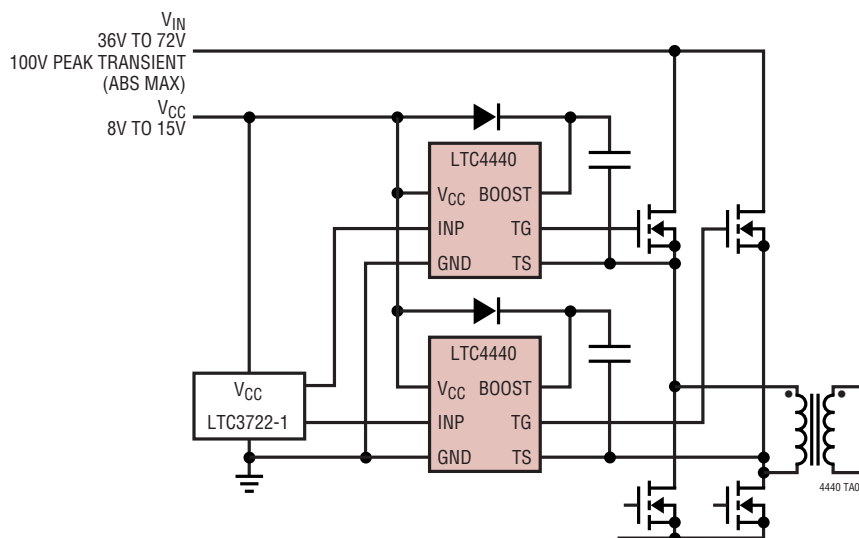
The LTC4440 contains both high side and low side undervoltage lockout circuits that disable the external MOSFET when activated.

The LTC4440 is available in the low profile (1mm) SOT-23 and thermally enhanced 8-lead MSOP packages.

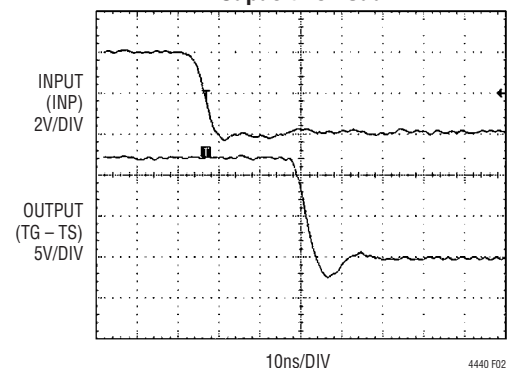
LT, LTC and LT are registered trademarks of Linear Technology Corporation.  
ThinSOT is a trademark of Linear Technology Corporation.  
Protected by U.S. Patents, including 6677210.

## TYPICAL APPLICATION

### Synchronous Phase-Modulated Full-Bridge Converter



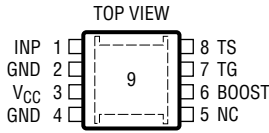
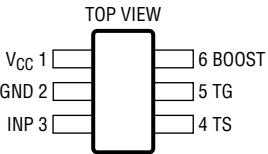
**LTC4440 Driving a 1000pF  
Capacitive Load**



## ABSOLUTE MAXIMUM RATINGS (Note 1)

|                                  |               |                                             |                |
|----------------------------------|---------------|---------------------------------------------|----------------|
| Supply Voltage                   |               | Peak Output Current < 1 $\mu$ s (TG) .....  | 4A             |
| $V_{CC}$ .....                   | -0.3V to 15V  | Driver Output TG (with Respect to TS) ..... | -0.3V to 15V   |
| BOOST – TS .....                 | -0.3V to 15V  | Operating Ambient Temperature Range         |                |
| INP Voltage .....                | -0.3V to 15V  | (Note 2) .....                              | -40°C to 85°C  |
| BOOST Voltage (Continuous) ..... | -0.3V to 95V  | Junction Temperature (Note 3) .....         | 125°C          |
| BOOST Voltage (100ms) .....      | -0.3V to 115V | Storage Temperature Range .....             | -65°C to 150°C |
| TS Voltage (Continuous) .....    | -5V to 80V    | Lead Temperature (Soldering, 10 sec) .....  | 300°C          |
| TS Voltage (100ms) .....         | -5V to 100V   |                                             |                |

## PACKAGE/ORDER INFORMATION

|                                                                                                                                                                                                                                                                                                          |                      |                                                                                                                                                                                                                                     |                    |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|
|  <p>MS8E PACKAGE<br/>8-LEAD PLASTIC MSOP</p> <p><math>T_{JMAX} = 125^{\circ}\text{C}</math>, <math>\theta_{JA} = 40^{\circ}\text{C/W}</math> (NOTE 4)</p> <p>EXPOSED PAD IS GND (PIN 9)<br/>MUST BE SOLDERED TO PCB</p> | ORDER PART NUMBER    |  <p>S6 PACKAGE<br/>6-LEAD PLASTIC SOT-23</p> <p><math>T_{JMAX} = 125^{\circ}\text{C}</math>, <math>\theta_{JA} = 230^{\circ}\text{C/W}</math></p> | ORDER PART NUMBER  |
|                                                                                                                                                                                                                                                                                                          | LTC4440EMS8E         |                                                                                                                                                                                                                                     | LTC4440ES6         |
|                                                                                                                                                                                                                                                                                                          | MS8E<br>PART MARKING |                                                                                                                                                                                                                                     | S6<br>PART MARKING |
|                                                                                                                                                                                                                                                                                                          | LTF9                 |                                                                                                                                                                                                                                     | LTZY               |

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}\text{C}$ .  $V_{CC} = V_{BOOST} = 12\text{V}$ ,  $V_{TS} = \text{GND} = 0\text{V}$ , unless otherwise noted.

| SYMBOL                            | PARAMETER                                     | CONDITIONS                                                                                                         |        | MIN          | TYP        | MAX          | UNITS        |
|-----------------------------------|-----------------------------------------------|--------------------------------------------------------------------------------------------------------------------|--------|--------------|------------|--------------|--------------|
| Main Supply (V <sub>CC</sub> )    |                                               |                                                                                                                    |        |              |            |              |              |
| I <sub>VCC</sub>                  | DC Supply Current<br>Normal Operation<br>UVLO | INP = 0V<br>V <sub>CC</sub> < UVLO Threshold (Falling) – 0.1V                                                      |        |              | 250<br>25  | 400<br>80    | μA<br>μA     |
| UVLO                              | Undervoltage Lockout Threshold                | V <sub>CC</sub> Rising<br>V <sub>CC</sub> Falling<br>Hysteresis                                                    | ●<br>● | 5.7<br>5.4   | 6.5<br>6.2 | 7.3<br>7.0   | V<br>V<br>mV |
| Bootstrapped Supply (BOOST – TS)  |                                               |                                                                                                                    |        |              |            |              |              |
| I <sub>BOOST</sub>                | DC Supply Current<br>Normal Operation<br>UVLO | INP = 0V<br>V <sub>BOOST</sub> – V <sub>TS</sub> < UVLO <sub>HS</sub> (FALLING) – 0.1V, V <sub>CC</sub> = INP = 5V |        |              | 110<br>86  | 180<br>170   | μA<br>μA     |
| UVLO <sub>HS</sub>                | Undervoltage Lockout Threshold                | V <sub>BOOST</sub> – V <sub>TS</sub> Rising<br>V <sub>BOOST</sub> – V <sub>TS</sub> Falling<br>Hysteresis          | ●<br>● | 6.75<br>6.25 | 7.4<br>6.9 | 7.95<br>7.60 | V<br>V<br>mV |
| Input Signal (INP)                |                                               |                                                                                                                    |        |              |            |              |              |
| V <sub>IH</sub>                   | High Input Threshold                          | INP Ramping High                                                                                                   | ●      | 1.3          | 1.6        | 2            | V            |
| V <sub>IL</sub>                   | Low Input Threshold                           | INP Ramping Low                                                                                                    | ●      | 0.85         | 1.25       | 1.6          | V            |
| V <sub>IH</sub> – V <sub>IL</sub> | Input Voltage Hysteresis                      |                                                                                                                    |        |              | 0.350      |              | V            |
| I <sub>INP</sub>                  | Input Pin Bias Current                        |                                                                                                                    |        |              | ±0.01      | ±2           | μA           |

## ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{CC} = V_{\text{BOOST}} = 12\text{V}$ ,  $V_{TS} = \text{GND} = 0\text{V}$ , unless otherwise noted.

| SYMBOL                         | PARAMETER                         | CONDITIONS                                                      | MIN | TYP       | MAX | UNITS    |
|--------------------------------|-----------------------------------|-----------------------------------------------------------------|-----|-----------|-----|----------|
| <b>Output Gate Driver (TG)</b> |                                   |                                                                 |     |           |     |          |
| $V_{OH}$                       | High Output Voltage               | $I_{TG} = -10\text{mA}$ , $V_{OH} = V_{\text{BOOST}} - V_{TG}$  |     | 0.7       |     | V        |
| $V_{OL}$                       | Low Output Voltage                | $I_{TG} = 100\text{mA}$                                         | ●   | 150       | 220 | mV       |
| $I_{PU}$                       | Peak Pull-Up Current              |                                                                 | ●   | 1.7       | 2.4 | A        |
| $R_{DS}$                       | Output Pull-Down Resistance       |                                                                 | ●   | 1.5       | 2.2 | $\Omega$ |
| <b>Switching Timing</b>        |                                   |                                                                 |     |           |     |          |
| $t_r$                          | Output Rise Time                  | 10% – 90%, $C_L = 1\text{nF}$<br>10% – 90%, $C_L = 10\text{nF}$ |     | 10<br>100 |     | ns<br>ns |
| $t_f$                          | Output Fall Time                  | 10% – 90%, $C_L = 1\text{nF}$<br>10% – 90%, $C_L = 10\text{nF}$ |     | 7<br>70   |     | ns<br>ns |
| $t_{PLH}$                      | Output Low-High Propagation Delay |                                                                 | ●   | 30        | 65  | ns       |
| $t_{PHL}$                      | Output High-Low Propagation Delay |                                                                 | ●   | 28        | 65  | ns       |

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** The LTC4440 is guaranteed to meet performance specifications from  $0^\circ\text{C}$  to  $70^\circ\text{C}$ . Specifications over the  $-40^\circ\text{C}$  to  $85^\circ\text{C}$  operating temperature range are assured by design, characterization and correlation with statistical process controls.

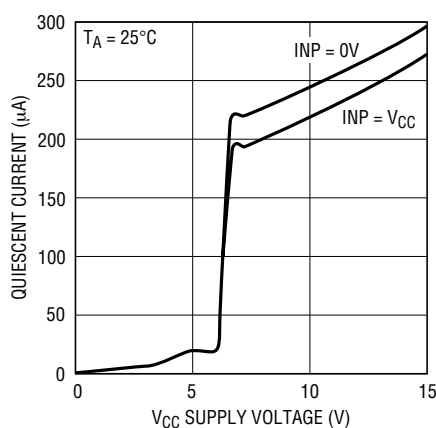
**Note 3:**  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $PD$  according to the following formula:

$$T_J = T_A + (PD \cdot \theta_{JA}^\circ\text{C/W})$$

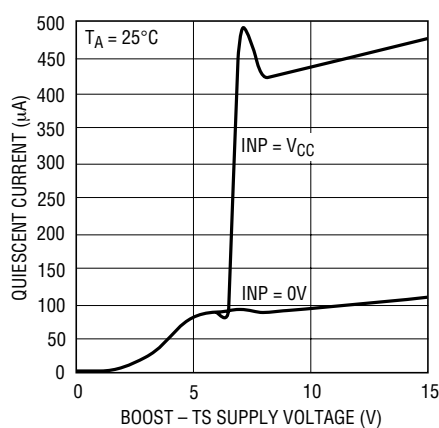
**Note 4:** Failure to solder the exposed back side of the MS8E package to the PC board will result in a thermal resistance much higher than  $40^\circ\text{C/W}$ .

## TYPICAL PERFORMANCE CHARACTERISTICS

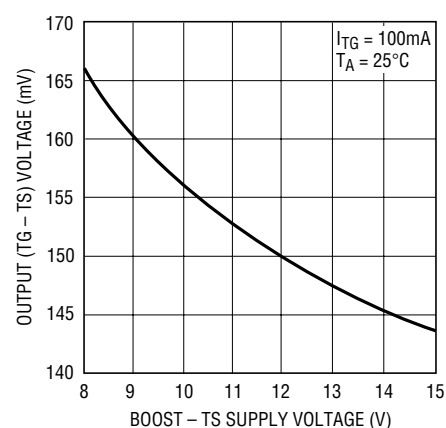
**$V_{CC}$  Supply Quiescent Current vs Voltage**



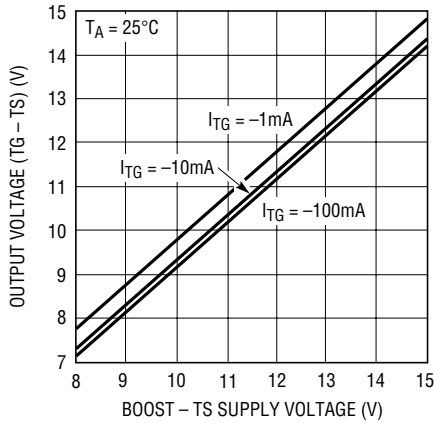
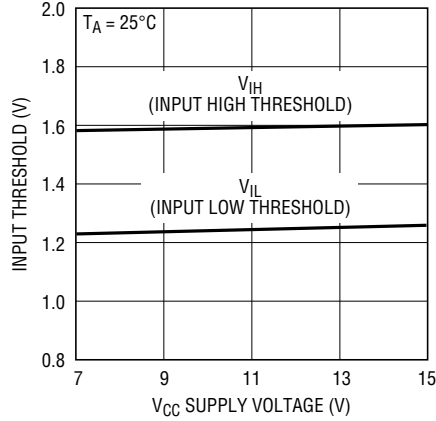
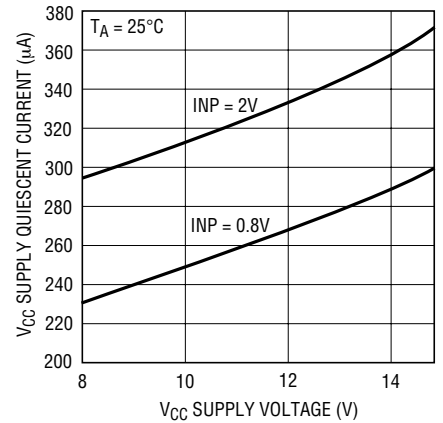
**BOOST – TS Supply Quiescent Current vs Voltage**



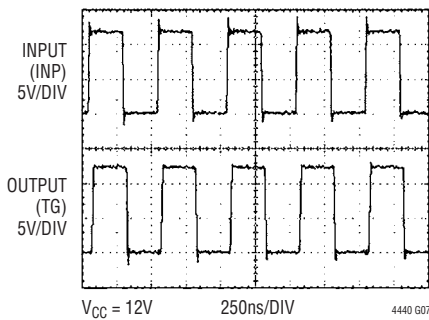
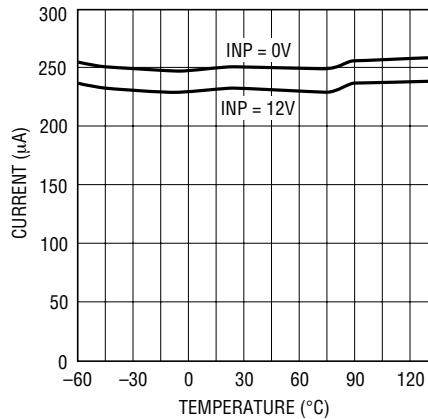
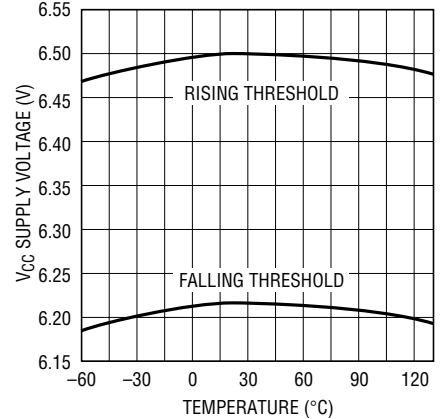
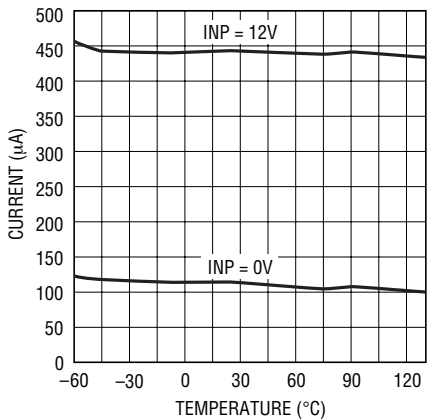
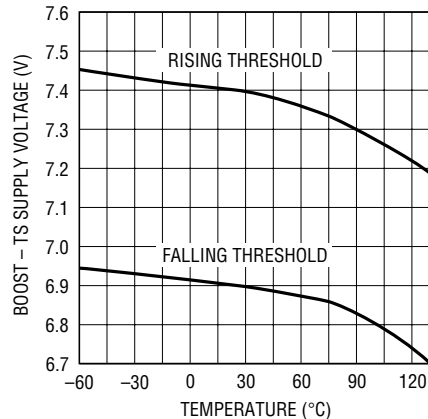
**Output Low Voltage ( $V_{OL}$ ) vs Supply Voltage**



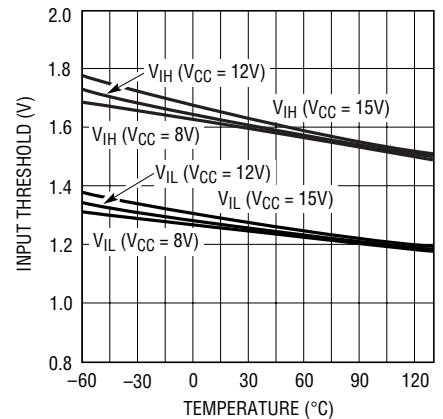
## TYPICAL PERFORMANCE CHARACTERISTICS

Output High Voltage ( $V_{OH}$ )  
vs Supply VoltageInput Thresholds (INP)  
vs Supply Voltage $V_{CC}$  Supply Current  
at TTL Input Levels

2MHz Operation

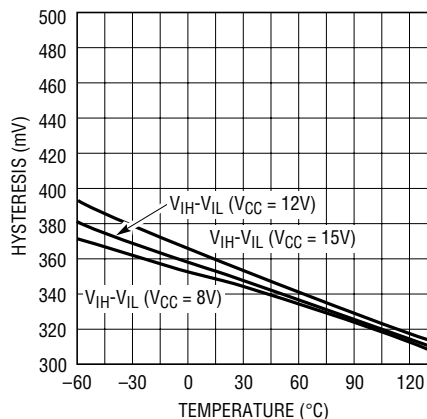
 $V_{CC}$  Supply Current ( $V_{CC} = 12\text{V}$ )  
vs Temperature $V_{CC}$  Undervoltage Lockout  
Thresholds vs TemperatureBoost Supply Current  
vs TemperatureBoost Supply (BOOST - TS)  
Undervoltage Lockout Thresholds  
vs Temperature

Input Threshold vs Temperature

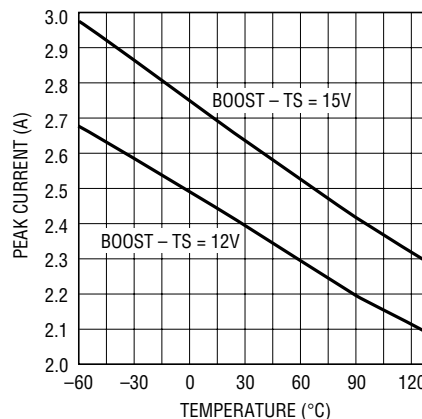


## TYPICAL PERFORMANCE CHARACTERISTICS

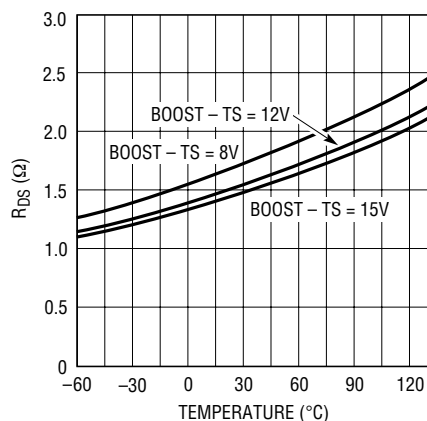
Input Threshold Hysteresis  
vs Temperature



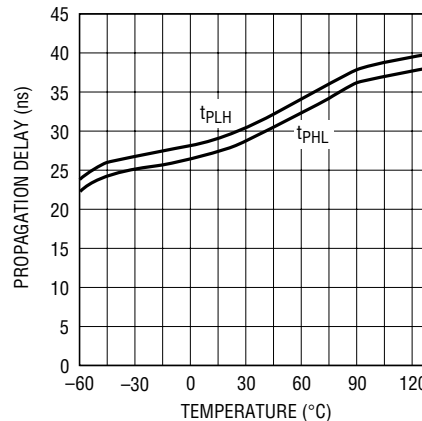
Peak Driver (TG) Pull-Up Current  
vs Temperature



Output Driver Pull-Down  
Resistance vs Temperature



Propagation Delay vs Temperature  
(V<sub>CC</sub> = BOOST = 12V)



## PIN FUNCTIONS

### SOT-23 Package

**V<sub>CC</sub> (Pin 1):** Chip Supply. This pin powers the internal low side circuitry. A low ESR ceramic bypass capacitor should be tied between this pin and the GND pin (Pin 2).

**GND (Pin 2):** Chip Ground.

**INP (Pin 3):** Input Signal. TTL/CMOS compatible input referenced to GND (Pin 2).

**TS (Pin 4):** Top (High Side) Source Connection.

**TG (Pin 5):** High Current Gate Driver Output (Top Gate). This pin swings between TS and BOOST.

**BOOST (Pin 6):** High Side Bootstrapped Supply. An external capacitor should be tied between this pin and TS (Pin 4). Normally, a bootstrap diode is connected between V<sub>CC</sub> (Pin 1) and this pin. Voltage swing at this pin is from V<sub>CC</sub> - V<sub>D</sub> to V<sub>IN</sub> + V<sub>CC</sub> - V<sub>D</sub>, where V<sub>D</sub> is the forward voltage drop of the bootstrap diode.

## PIN FUNCTIONS

### Exposed Pad MS8E Package

**INP (Pin 1):** Input Signal. TTL/CMOS compatible input referenced to GND (Pin 2).

**GND (Pins 2, 4):** Chip Ground.

**V<sub>CC</sub> (Pin 3):** Chip Supply. This pin powers the internal low side circuitry. A low ESR ceramic bypass capacitor should be tied between this pin and the GND pin (Pin 2).

**NC (Pin 5):** No Connect. No connection required. For convenience, this pin may be tied to Pin 6 (BOOST) on the application board.

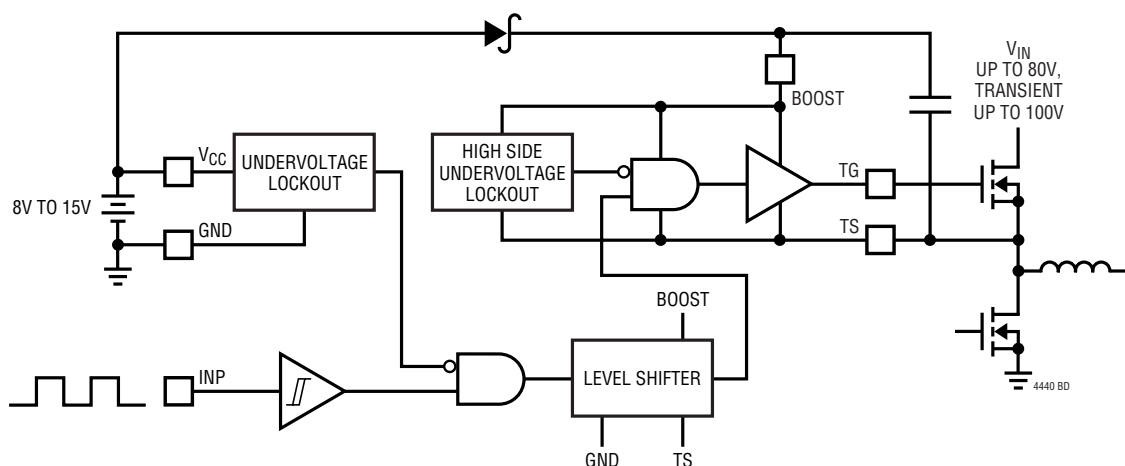
**BOOST (Pin 6):** High Side Bootstrapped Supply. An external capacitor should be tied between this pin and TS (Pin 8). Normally, a bootstrap diode is connected between V<sub>CC</sub> (Pin 3) and this pin. Voltage swing at this pin is from V<sub>CC</sub> – V<sub>D</sub> to V<sub>IN</sub> + V<sub>CC</sub> – V<sub>D</sub>, where V<sub>D</sub> is the forward voltage drop of the bootstrap diode.

**TG (Pin 7):** High Current Gate Driver Output (Top Gate). This pin swings between TS and BOOST.

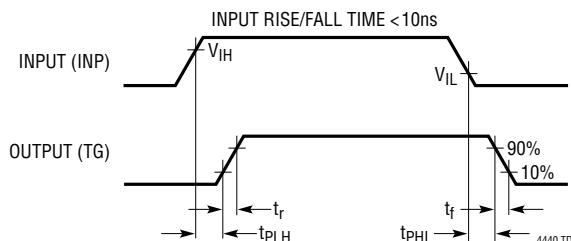
**TS (Pin 8):** Top (High Side) Source Connection.

**Exposed Pad (Pin 9):** Ground. Must be electrically connected to Pins 2 and 4 and soldered to PCB ground for optimum thermal performance.

## BLOCK DIAGRAM



## TIMING DIAGRAM







## APPLICATIONS INFORMATION

### Power Dissipation

To ensure proper operation and long-term reliability, the LTC4440 must not operate beyond its maximum temperature rating. Package junction temperature can be calculated by:

$$T_J = T_A + PD (\theta_{JA})$$

where:

$T_J$  = Junction Temperature

$T_A$  = Ambient Temperature

PD = Power Dissipation

$\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

Power dissipation consists of standby and switching power losses:

$$PD = P_{STDBY} + P_{AC}$$

where:

$P_{STDBY}$  = Standby Power Losses

$P_{AC}$  = AC Switching Losses

The LTC4440 consumes very little current during standby. The DC power loss at  $V_{CC} = 12V$  and  $V_{BOOST-TS} = 12V$  is only  $(250\mu A + 110\mu A)(12V) = 4.32mW$ .

AC switching losses are made up of the output capacitive load losses and the transition state losses. The capacitive load losses are primarily due to the large AC currents needed to charge and discharge the load capacitance during switching. Load losses for the output driver driving a pure capacitive load  $C_{OUT}$  would be:

$$\text{Load Capacitive Power} = (C_{OUT})(f)(V_{BOOST-TS})^2$$

The power MOSFET's gate capacitance seen by the driver output varies with its  $V_{GS}$  voltage level during switching. A power MOSFET's capacitive load power dissipation can be calculated using its gate charge,  $Q_G$ . The  $Q_G$  value corresponding to the MOSFET's  $V_{GS}$  value ( $V_{CC}$  in this case) can be readily obtained from the manufacturer's  $Q_G$  vs  $V_{GS}$  curves:

$$\text{Load Capacitive Power (MOS)} = (V_{BOOST-TS})(Q_G)(f)$$

Transition state power losses are due to both AC currents required to charge and discharge the driver's internal nodal capacitances and cross-conduction currents in the internal gates.

### Undervoltage Lockout (UVLO)

The LTC4440 contains both low side and high side undervoltage lockout detectors that monitor  $V_{CC}$  and the bootstrapped supply  $V_{BOOST-TS}$ . When  $V_{CC}$  falls below 6.2V, the internal buffer is disabled and the output pin OUT is pulled down to TS. When  $V_{BOOST-TS}$  falls below 6.9V, OUT is pulled down to TS. When both supplies are undervoltage, OUT is pulled low to TS and the chip enters a low current mode, drawing approximately 25 $\mu A$  from  $V_{CC}$  and 86 $\mu A$  from BOOST.

### Bypassing and Grounding

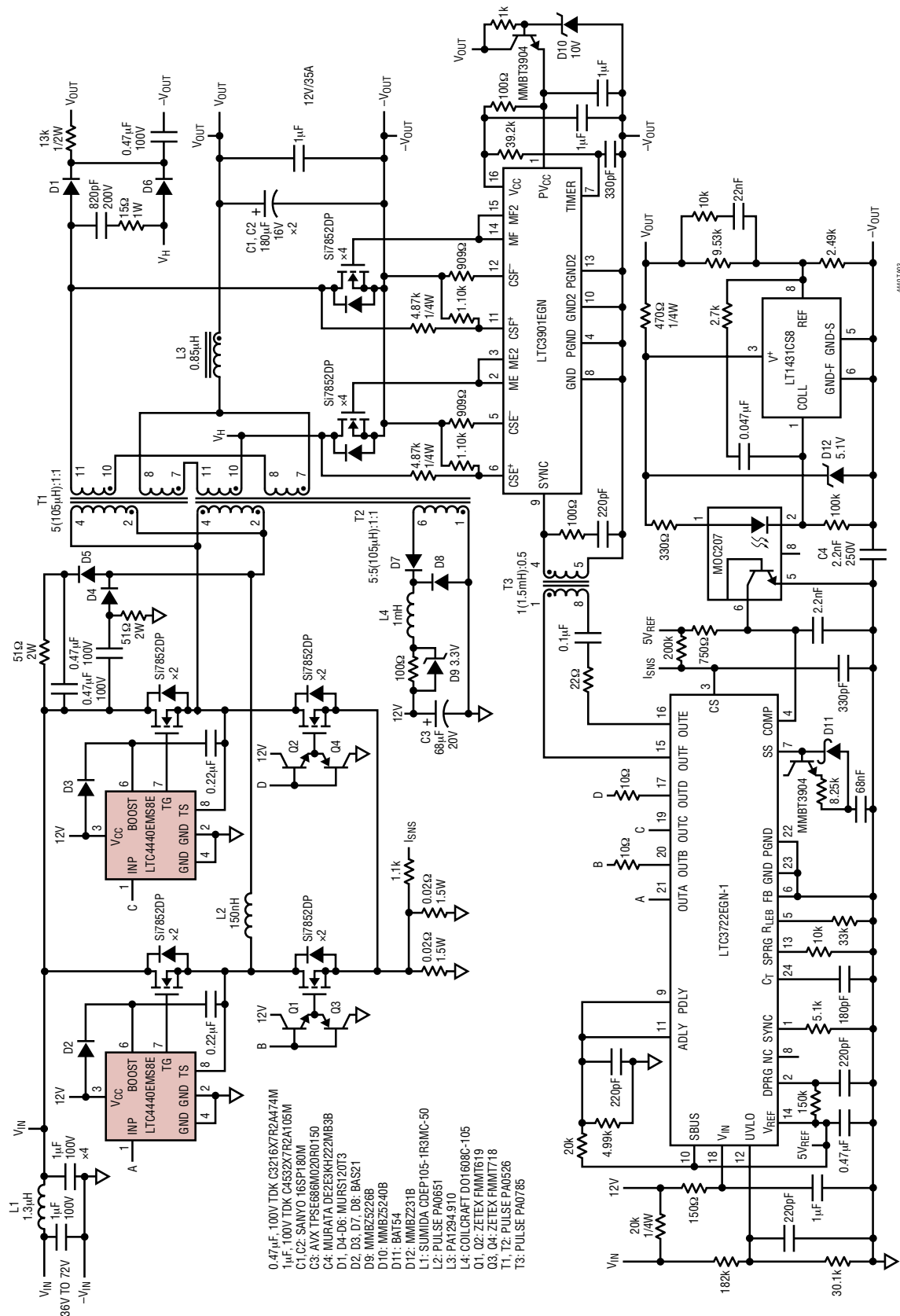
The LTC4440 requires proper bypassing on the  $V_{CC}$  and  $V_{BOOST-TS}$  supplies due to its high speed switching (nanoseconds) and large AC currents (Amperes). Careless component placement and PCB trace routing may cause excessive ringing and under/overshoot.

To obtain the optimum performance from the LTC4440:

- Mount the bypass capacitors as close as possible between the  $V_{CC}$  and GND pins and the BOOST and TS pins. The leads should be shortened as much as possible to reduce lead inductance.
- Use a low inductance, low impedance ground plane to reduce any ground drop and stray capacitance. Remember that the LTC4440 switches >2A peak currents and any significant ground drop will degrade signal integrity.
- Plan the power/ground routing carefully. Know where the large load switching current is coming from and going to. Maintain separate ground return paths for the input pin and the output power stage.
- Keep the copper trace between the driver output pin and the load short and wide.
- When using the MS8E package, be sure to solder the exposed pad on the back side of the LTC4440 package to the board. Correctly soldered to a 2500mm<sup>2</sup> double-sided 1oz copper board, the LTC4440 has a thermal resistance of approximately 40°C/W. Failure to make good thermal contact between the exposed back side and the copper board will result in thermal resistances far greater than 40°C/W.



## TYPICAL APPLICATIONS

LTC3722/LTC4440 420W 36V-72V<sub>IN</sub> to 12V/35A Isolated Full-Bridge Supply

4440 TA03

**Efficiency (%) vs. Load Current (A)**

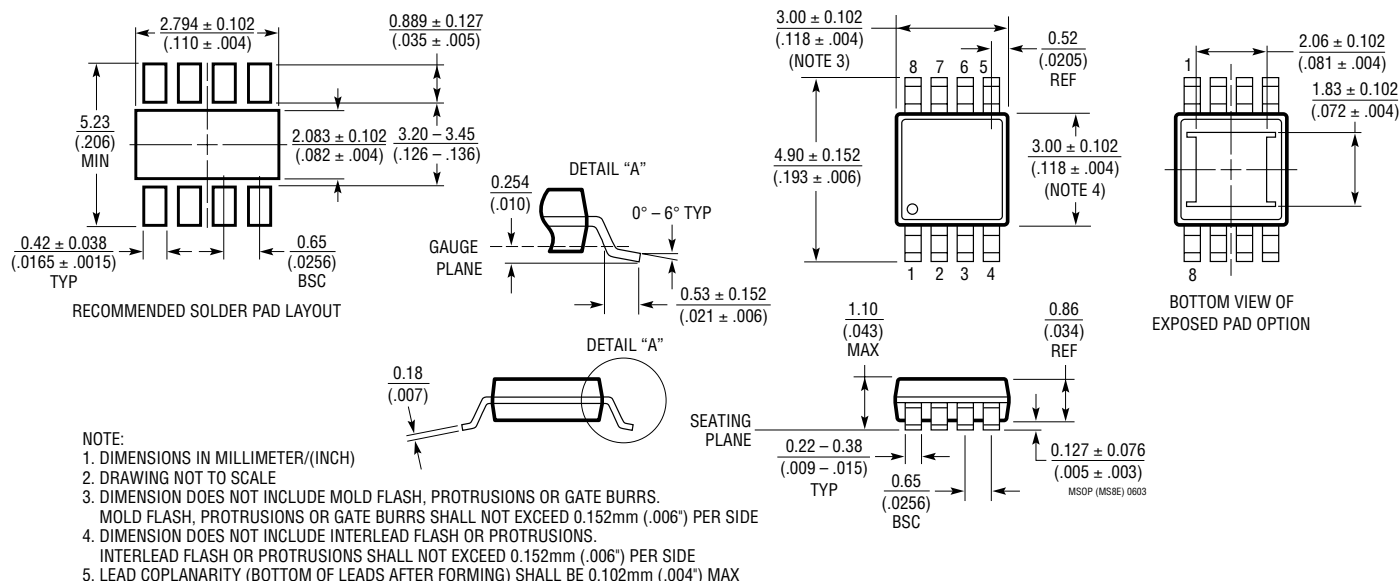
| Load Current (A) | Efficiency (%) at 42V <sub>OUT</sub> | Efficiency (%) at 48V <sub>OUT</sub> | Efficiency (%) at 56V <sub>OUT</sub> |
|------------------|--------------------------------------|--------------------------------------|--------------------------------------|
| 6                | 93.5                                 | 94.5                                 | 95.5                                 |
| 8                | 94.0                                 | 95.0                                 | 96.0                                 |
| 10               | 94.5                                 | 95.5                                 | 96.5                                 |
| 12               | 95.0                                 | 96.0                                 | 97.0                                 |
| 14               | 95.5                                 | 96.5                                 | 97.5                                 |
| 16               | 96.0                                 | 97.0                                 | 98.0                                 |
| 18               | 96.5                                 | 97.5                                 | 98.5                                 |
| 20               | 97.0                                 | 98.0                                 | 99.0                                 |

**Parts List:**

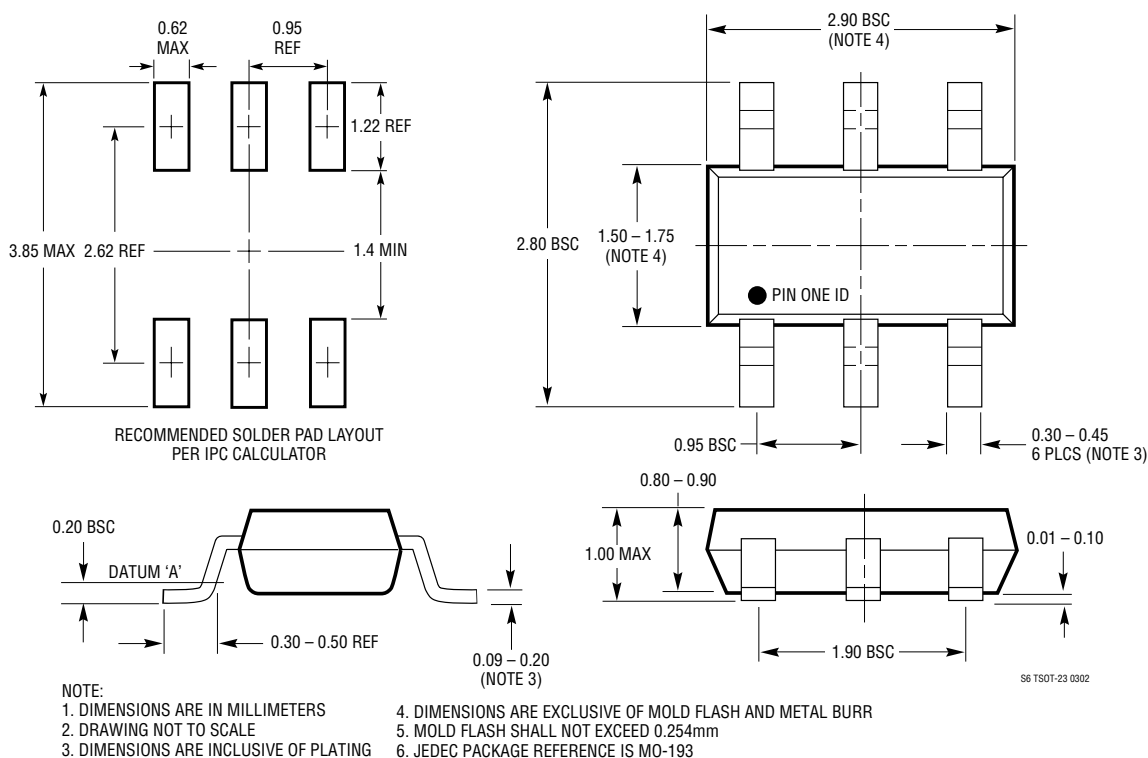
- L1: 100V TDK C325X7R2A105M
- C1, C2: SANYO 1610C47M
- C3: AVX TPSE686M020R0150
- C4: MURATA GHM3045X7R22K-6C
- D3: DIODES INC. ES1B
- D3-D6: BAS21
- D7, D8: MMBZ5240B
- L4: COILCRAFT D01608C-105
- L5: COILCRAFT D01813P-561HC
- L6: PULSE PAT294.132 OR PANASONIC ETOP1H1R0BFA
- R1, R2: IRC LFC0512-R03G
- T1: PULSE PA0805.004
- T2: PULSE PA0705

# PACKAGE DESCRIPTION

## MS8E Package 8-Lead Plastic MSOP (Reference LTC DWG # 05-08-1662)

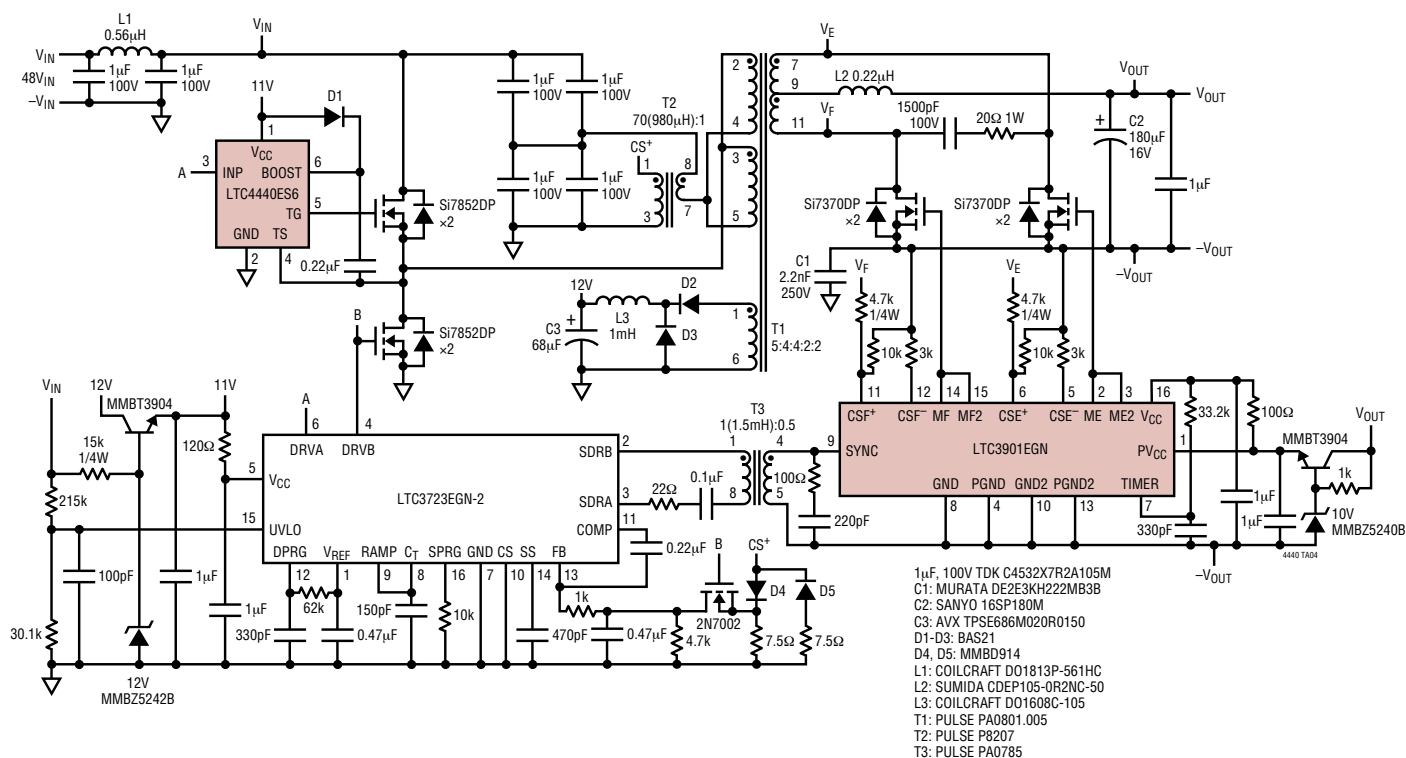


## S6 Package 6-Lead Plastic SOT-23 (Reference LTC DWG # 05-08-1636)



S6 TSOT-23 0302

## TYPICAL APPLICATION

LTC3723-2/LTC4440/LTC3901 240W 42V-56V<sub>IN</sub> to Unregulated 12V Half-Bridge Converter

## RELATED PARTS

| PART NUMBER             | DESCRIPTION                                                                | COMMENTS                                                                                                                            |
|-------------------------|----------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|
| LTC1155                 | Dual Micropower High/Low Side Drivers with Internal Charge Pump            | 4.5V to 18V Supply Range                                                                                                            |
| LT®1161                 | Quad Protected High Side MOSFET Driver                                     | 8V to 48V Supply Range, $t_{ON} = 200\mu s$ , $t_{OFF} = 28\mu s$                                                                   |
| LTC1163                 | Triple 1.8V to 6V High Side MOSFET Driver                                  | 1.8V to 6V Supply Range, $t_{ON} = 95\mu s$ , $t_{OFF} = 45\mu s$                                                                   |
| LT1339                  | High Power Synchronous DC/DC Controller                                    | Current Mode Operation Up to 60V, Dual N-Channel Synchronous Drive                                                                  |
| LTC1535                 | Isolated RS485 Transceiver                                                 | 2500V <sub>RMS</sub> of Isolation Between Line Transceiver and Logic Level Interface                                                |
| LTC1693 Family          | High Speed Dual MOSFET Drivers                                             | 1.5A Peak Output Current, $4.5V \leq V_{IN} \leq 13.2V$                                                                             |
| LT3010/LT3010-5         | 50mA, 3V to 80V Low Dropout Micropower Regulators                          | Low Quiescent Current (30 $\mu$ A), Stable with Small (1 $\mu$ F) Ceramic Capacitor                                                 |
| LT3430                  | High Voltage, 3A, 200kHz Step-Down Switching Regulator                     | Input Voltages Up to 60V, Internal 0.1 $\Omega$ Power Switch, Current Mode Architecture, 16-Pin Exposed Pad TSSOP Package           |
| LTC3722-1/<br>LTC3722-2 | Synchronous Dual Mode Phase Modulated Full-Bridge Controllers              | Adaptive Zero Voltage Switching, High Output Power Levels (Up to Kilowatts)                                                         |
| LTC3723-1/<br>LTC3723-2 | Synchronous Push-Pull PWM Controllers                                      | Current Mode or Voltage Mode Push-Pull Controllers                                                                                  |
| LT3781/LTC1698          | 36V to 72V Input Isolated DC/DC Converter Chip Set                         | Synchronous Rectification; Overcurrent, Overvoltage, UVLO Protection; Power Good Output Signal; Voltage Margining; Compact Solution |
| LT3804                  | Secondary Side Dual Output Controller with Opto Driver                     | Regulates Two Secondary Outputs, Optocoupler Feedback Divider and Second Output Synchronous Driver Controller                       |
| LTC3900                 | Synchronous Rectifier Driver for Forward Converters                        | Programmable Time Out, Reverse Inductor Current Sense                                                                               |
| LTC3901                 | Secondary Side Synchronous Driver for Push-Pull and Full-Bridge Converters | Programmable Time Out, Reverse Inductor Current Sense                                                                               |
| LTC4441                 | 6A MOSFET Driver                                                           | Adjustable Gate Drive from 5V to 8V, $5V \leq V_{IN} \leq 28V$                                                                      |